

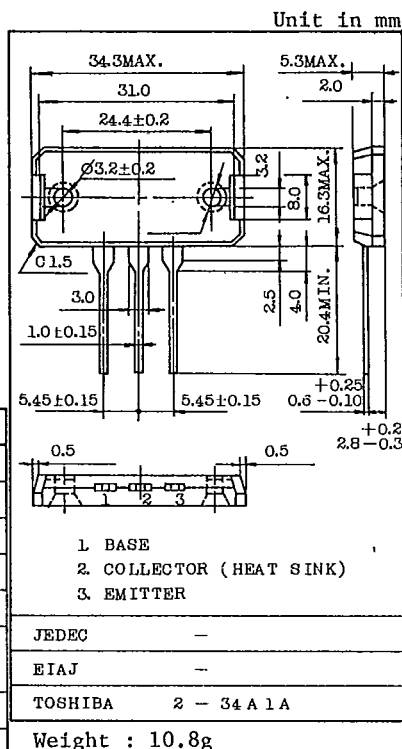
POWER AMPLIFIER APPLICATIONS.

FEATURES:

- High Breakdown Voltage : $V_{CEO}=160V$
- High Transition Frequency : $f_T=80MHz$ (Typ.)
- Complementary to 2SA1095.
- Recommended for 100W High-Fidelity Audio Frequency Amplifier Output Stage.

MAXIMUM RATINGS (Ta=25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	160	V
Collector-Emitter Voltage	V_{CEO}	160	V
Emitter-Base Voltage	V_{EBO}	5	V
Collector Current	I_C	15	A
Emitter Current	I_E	-15	A
Collector Power Dissipation (Tc=25°C)	P_C	150	W
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_{stg}	-55~150	°C



ELECTRICAL CHARACTERISTICS (Ta=25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB}=160V, I_E=0$	-	-	50	μA
Emitter Cut-off Current	I_{EBO}	$V_{EB}=5V, I_C=0$	-	-	50	μA
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=0.1A, I_B=0$	160	-	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=0.01A, I_C=0$	5	-	-	V
DC Current Gain	$h_{FE(1)}$ (Note)	$V_{CE}=5V, I_C=1A$	55	-	240	
	$h_{FE(2)}$	$V_{CE}=5V, I_C=5A$	40	-	-	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=5A, I_B=0.5A$	-	-	2.0	V
Base-Emitter Voltage	V_{BE}	$V_{CE}=5V, I_C=5A$	-	-	2.0	V
Transition Frequency	f_T	$V_{CE}=10V, I_C=1A$	-	80	-	MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=10V, I_E=0, f=1MHz$	-	200	-	pF

Note : $h_{FE(1)}$ Classification R : 55~110, O : 80~160, Y : 120~240

